onsemi

3.3 V LVDS High Speed Differential Driver/Receiver

FIN1019

General Description

This driver and receiver pair are designed for high speed interconnects utilizing Low Voltage Differential Signaling (LVDS) technology. The driver translates LVTTL signals to LVDS levels with a typical differential output swing of 350 mV and the receiver translates LVDS signals, with a typical differential input threshold of 100 mV, into LVTTL levels. LVDS technology provides low EMI at ultra low power dissipation even at high frequencies. This device is ideal for high speed clock or data transfer.

Features

- Greater than 400 Mbs Data Rate
- 3.3 V Power Supply Operation
- 0.5 ns Maximum Differential Pulse Skew
- 2.5 ns Maximum Propagation Delay
- Low Power Dissipation
- Power–Off Protection
- 100 mV Receiver Input Sensitivity
- Fail Safe Protection Open-circuit, Shorted and Terminated Conditions
- Meets or Exceeds the TIA/EIA-644 LVDS Standard
- Flow-through Pinout Simplifies PCB Layout
- 14–Lead TSSOP Package Save Space
- This Device is Pb-Free, Halide Free and is RoHS Compliant

FUNCTION TABLE

R _{IN+}	RI	۱–	RE	R _{OUT}	
L	Н	l	L	L	-
Н	L		L	Н	
Х	Х		Н	Z	
Fa	Fail Safe Conditi		L	Н	
D	D _{IN}		DE		D _{OUT-}
	L		н		Н
ŀ	Н		1	Н	L
)	Х		-	Z	Z
Open–Circuit or Z		ŀ	1	L	Н

H = HIGH Logic Level Z = High Impedance L = LOW Logic Level X = Don't Care Fail Safe = Open, Shorted, Terminated







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ORDERING INFORMATION

Order Number	Package	Shipping [†]
FIN1019MTCX	TSSOP-14 WB (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PIN DESCRIPTIONS

Pin Name	Description
D _{IN}	LVTTL Data Input
D _{OUT+}	Non-inverting LVDS Output
D _{OUT} -	Inverting LVDS Output
DE	Driver Enable (LVTTL, Active HIGH)
R _{IN+}	Non–Inverting LVDS Input
R _{IN-}	Inverting LVDS Input
R _{OUT}	LVTTL Receiver Output
RE	Receiver Enable (LVTTL, Active LOW)
V _{CC}	Power Supply
GND	Ground
NC	No Connect

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	–0.5 V to +4.6 V
D _{IN} , DE, RE	LVTTL DC Input Voltage	–0.5 V to +6 V
R _{IN+} , R _{IN-}	LVDS DC Input Voltage	–0.5 V to 4.7 V
R _{OUT}	LVTTL DC Output Voltage	–0.5 V to +6 V
D _{OUT+} , D _{OUT-}	LVDS DC Output Voltage	–0.5 V to 4.7 V
I _{OSD}	LVDS Driver Short Circuit Current	Continuous
Ι _Ο	LVTTL DC Output Current	16 mA
T _{STG}	Storage Temperature Range	–65°C to +150°C
TJ	Max Junction Temperature	150°C
TL	Lead Temperature (Soldering, 10 Seconds)	260°C
	ESD (Human Body Model)	≥6500 V
	ESD (Machine Model)	≥300 V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value
V _{CC}	Supply Voltage	3.0 V to 3.6 V
V _{IN}	Input Voltage	0 to V _{CC}
V _{ID}	Magnitude of Differential Voltage	100 mV to V _{CC}
V _{IC}	Common-Mode Input Voltage	0.05 V to 2.35 V
T _A	Operating Temperature	–40°C to +85°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS (Over supply voltage and operating temperature ranges, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ (Note 1)	Max	Unit
-	FFERENTIAL DRIVER CHARACTE					-
V _{OD}	Output Differential Voltage	$R_{L} = 100 \Omega$, See Figure 1	250	350	450	mV
ΔV_{OD}	V _{OD} Magnitude Change from Differential LOW-to-HIGH		-	-	25	mV
V _{OS}	Offset Voltage		1.125	1.25	1.375	V
ΔV_{OS}	Offset Magnitude Change from Differential LOW-to-HIGH		-	-	25	mV
I _{OZD}	Disabled Output Leakage Current	$V_{OUT} = V_{CC}$ or GND, DE = 0 V	-	-	±20	μA
I _{OFF}	Power Off Output Current	V _{CC} = 0 V, V _{OUT} = 0 V or 3.6 V	-	-	±20	μA
I _{OS}	Short Circuit Output Current	$V_{OUT} = 0 V, DE = V_{CC}$	-	-	-8	mA
		$V_{OD} = 0 V, DE = V_{CC}$	_	_	±8	1
LVTTL D	RIVER CHARACTERISTICS			L U		
V _{OH}	Output HIGH Voltage	$I_{OH} = -100 \ \mu\text{A}$, $\overline{\text{RE}} = 0 \text{ V}$, See Figure 6 and Table 1	V _{CC} – 0.2	-	_	V
		$I_{OH} = -8 \text{ mA}, \overline{RE} = 0 \text{ V}, \text{ V}_{ID} = 400 \text{ mV}$ V _{ID} = 400 mV, V _{IC} = 1.2 V, see Figure 6	2.4	-	_	1
V _{OL}	Output LOW Voltage	I_{OL} = 100 $\mu A, \ensuremath{\overline{RE}}$ = 0 V, V_{ID} = –400 mV See Figure 6 and Table 1	-	-	0.2	V
		$I_{OL} = -8 \text{ mA}, \overline{RE} = 0 \text{ V}, \text{ V}_{ID} = -400 \text{ mV}$ $V_{ID} = -400 \text{ mV}, \text{ V}_{IC} = 1.2 \text{ V}, \text{ see Figure 6}$	-	-	0.5	
I _{OZ}	Disabled Output Leakage Current	$V_{OUT} = V_{CC}$ or GND, $\overline{RE} = V_{CC}$	-	-	±20	μA
LVDS RE	ECEIVER CHARACTERISTICS	·				
V _{TH}	Differential Input Threshold HIGH	See Figure 6 and Table 1	-	-	100	mV
V_{TL}	Differential Input Threshold LOW	See Figure 6 and Table 1	-100	-	-	mV
I _{IN}	Input Current	$V_{IN} = 0 V \text{ or } V_{CC}$	-	-	±20	μA
I _{I(OFF)}	Power–OFF Input Current	V _{CC} = 0 V, V _{IN} = 0 V or 3.6 V	-	-	±20	μA
LVTTL D	RIVER AND CONTROL SIGNALS C	HARACTERISTICS	-			-
VIH	Input HIGH Voltage		2.0	-	V _{CC}	V
VIL	Input LOW Voltage		GND	-	0.8	V
I _{IN}	Input Current	$V_{IN} = 0 V \text{ or } V_{CC}$	-	-	±20	μA
I _{I(OFF)}	Power–OFF Input Current	V _{CC} = 0 V, V _{IN} = 0 V or 3.6 V	-	-	±20	μA
V _{IK}	Input Clamp Voltage	I _{IK} = -18 mA	-1.5	-	-	V
DEVICE	CHARACTERISTICS	•	-			-
I _{CC}	Power Supply Current	Driver Enabled, Driver Load: $R_L = 100 \Omega$ Receiver Disabled, No Receiver Load	-	-	12.5	mA
		Driver Enabled, Driver Load: $R_L = 100 \Omega$, Receiver Enabled, ($R_{IN+} = 1 V$ and $R_{IN-} = 1.4 V$) or ($R_{IN+} = 1.4 V$ and $R_{OUT-} = 1 V$)	-	-	12.5	mA
		Driver Disabled, Receiver Enabled, (R _{IN+} = 1 V and R _{IN-} = 1.4 V) or (R _{IN+} = 1.4 V and R _{IN-} = 1 V)	-	-	7.0	mA
		Driver Disabled, Receiver Disabled	-	-	7.0	mA
CIN	Input Capacitance	Any LVTTL or LVDS Input	-	4	_	pF
C _{OUT}	Output Capacitance	Any LVTTL or LVDS Output	-	6	_	pF

COUTOutput CapacitanceAny LVTTL1. All typical values are at $T_A = 25^{\circ}C$ and with $V_{CC} = 3.3$ V.

AC ELECTRICAL CHARACTERISTICS (Over supply voltage and operating temperature ranges, unless otherwise	e specified)
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Symbol	Parameter	Test Conditions	Min	Typ (Note 2)	Max	Unit
DRIVER	TIMING CHARACTERISTICS					
t _{PLHD}	Differential Propagation Delay LOW-to-HIGH	R_L = 100 Ω, C_L = 10 pF, See Figure 2 and Figure 3	0.5	-	1.5	ns
t _{PHLD}	Differential Propagation Delay HIGH-to-LOW		0.5	-	1.5	ns
t _{TLHD}	Differential Output Rise Time (20% to 80%)		0.4	-	1.0	ns
t _{THLD}	Differential Output Fall Time (80% to 20%)		0.4	-	1.0	ns
t _{SK(P)}	Pulse Skew t _{PLH} – t _{PHL}		-	-	0.5	ns
t _{SK(PP)}	Part-to-Part Skew (Note 3)	$R_L = 100 \Omega$, $C_L = 10 pF$, See Figure 4 and Figure 5	-	-	1.0	ns
t _{ZHD}	Differential Output Enable Time from Z to HIGH		-	-	5.0	ns
t _{ZLD}	Differential Output Enable Time from Z to LOW		-	-	5.0	ns
t _{HZD}	Differential Output Disable Time from HIGH to Z		-	-	5.0	ns
t _{LZD}	Differential Output Disable Time from LOW to Z		-	-	5.0	ns
RECEIVE	R TIMING CHARACTERISTICS					
t _{PLH}	Propagation Delay LOW-to-HIGH	$ V_{ID} = 400 \text{ mV}, C_{L} = 10 \text{ pF},$	0.9	-	2.5	ns
t _{PHL}	Propagation Delay HIGH-to-LOW	See Figure 6 and Figure 7	0.9	-	2.5	ns
t _{TLH}	Output Rise Time (20% to 80%)		-	0.5	-	ns
t _{THL}	Output Fall Time (80% to 20%)]	-	0.5	-	ns
t _{SK(P)}	Pulse Skew t _{PLH} – t _{PHL}		-	-	0.5	ns
t _{SK(PP)}	Part-to-Part Skew (Note 3)]	-	-	1.0	ns
t _{ZH}	LVTTL Output Enable Time from Z to HIGH	$R_L = 500 \Omega$, $C_L = 10 pF$, See Figure 8	-	-	5.0	ns

LVTTL Output Disable Time from LOW to Z t_{LZ}

LVTTL Output Enable Time from Z to LOW

LVTTL Output Disable Time from HIGH to Z

2.

t_{ZL}

t_{HZ}

All typical values are at $T_A = 25^{\circ}$ C and with $V_{CC} = 5$ V. $t_{SK(PP)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices switching in the same direction (either LOW–to–HIGH or HIGH–to–LOW) when both devices operate with the same supply voltage, same temperature, and have 3. identical test circuits.

5.0

5.0

5.0

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ns

ns

ns



Figure 1. Differential Driver DC Test Circuit



NOTE A: Input pulses have frequency = 10 MHz, t_R or t_F = 2 ns NOTE B: C_L includes all probe and fixture capacitances

Figure 2. Differential Driver Propagation Delay and Transition Time Test Circuit



Figure 3. AC Waveforms for Differential Driver



NOTE B: Input pulses have the frequency = 10 MHz, t_R or t_F = 2 ns NOTE A: C_L includes all probe and fixture capacitances

Figure 4. Differential Driver Enable and Disable Test Circuit



Figure 5. Enable and Disable AC Waveforms



NOTE A: Input pulses have frequency = 10 MHz, tR or tF = 1 ns NOTE B: CL includes all probe and fixture capacitance

Figure 6. Differential Receiver Voltage Definitions and Propagation Delay and Transition Time Test Circuit

Applied Vo	Applied Voltages (V)		Resulting Common Mode Input Voltage (V)	
V _{IA}	V _{IB}	V _{ID}	V _{IC}	
1.25	1.15	100	1.2	
1.15	1.25	-100	1.2	
2.4	2.3	100	2.35	
2.3	2.4	-100	2.35	
0.1	0	100	0.05	
0	0.1	-100	0.05	
1.5	0.9	600	1.2	
0.9	1.5	-600	1.2	
2.4	1.8	600	2.1	
1.8	2.4	-600	2.1	
0.6	0	600	0.3	
0	0.6	-600	0.3	

Table 1. RECEIVER MINIMUM AND MAXIMUM INPUT THRESHOLD TEST VOLTAGES



Figure 7. LVDS Input to LVTTL Output AC Waveforms







Voltage Waveforms Enable and Disable Times

Figure 8. LVTTL Outputs Test Circuit and AC Waveforms

DC / AC TYPICAL PERFORMANCE CURVES







Figure 15. Power Supply Current vs. Frequency



Figure 16. Power Supply Current vs. Power Supply Voltage



Figure 17. Power Supply Current vs. Ambient Temperature



Figure 19. Differential Propagation Delay vs. Ambient Temperature



Figure 18. Differential Propagation Delay vs. Power Supply









Figure 22. Transition Time vs. Power Supply Voltage



Figure 23. Transition Times vs. Ambient Temperature

DC / AC TYPICAL PERFORMANCE CURVES

Receiver







Figure 26. Output Short Circuit Current vs. Power Supply Voltage







Figure 25. Output Low Voltage vs. Power Supply Voltage



Figure 27. Power Supply Current vs. Frequency



Figure 29. Power Supply Current vs. Ambient Temperature







Figure 31. Differential Propagation Delay vs. Ambient Temperature



Figure 32. Differential Skew (t_{PHL} – t_{PHL}) vs. Power Supply Voltage



Figure 34. Differential Propagation Delay vs. Differential Input Voltage







Figure 35. Differential Propagation Delay vs. Common–Mode Voltage





Figure 36. Transition Time vs. Power Supply Voltage





Figure 38. Differential Propagation Delay vs. Load



Figure 39. Transition Time vs. Load

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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